

FS10ASJ-3

High-Speed Switching Use Nch Power MOS FET

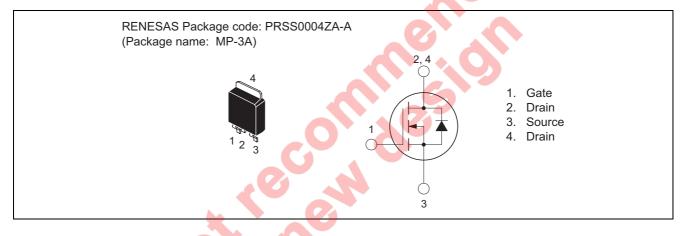
REJ03G1409-0200 (Previous: MEJ02G0078-0101) Rev.2.00 Aug 07, 2006

2500

Features

- Drive voltage : 4 V
- V_{DSS} : 150 V
- $r_{DS(ON) (max)}$: 160 m Ω
- I_D: 10 A
- Integrated Fast Recovery Diode (TYP.): 90 ns

Outline



Applications

Motor control, Lamp control, Solenoid control, DC-DC converters, etc.

Maximum Ratings

				$(\mathrm{Tc} = 25^{\circ}\mathrm{C})$
Parameter	Symbol	Ratings	Unit	Conditions
Drain-source voltage	V _{DSS}	150	V	$V_{GS} = 0 V$
Gate-source voltage	V _{GSS}	±20	V	$V_{DS} = 0 V$
Drain current	I _D	10	А	
Drain current (Pulsed)	I _{DM}	40	А	
Avalanche drain current (Pulsed)	I _{DA}	10	А	L = 100 μH
Source current	Is	10	А	
Source current (Pulsed)	I _{SM}	40	А	
Maximum power dissipation	PD	35	W	
Channel temperature	Tch	– 55 to +150	°C	
Storage temperature	Tstg	– 55 to +150	°C	
Mass	_	0.32	g	Typical value



Reverse recovery time

Electrical Characteristics

						$(Tch = 25^{\circ}C)$
Parameter	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain-source breakdown voltage	V _{(BR)DSS}	150	—	—	V	$I_D = 1 \text{ mA}, V_{GS} = 0 \text{ V}$
Gate-source leakage current	I _{GSS}	_	—	±0.1	μΑ	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$
Drain-source leakage current	I _{DSS}	—	—	0.1	mA	$V_{DS} = 150 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$
Gate-source threshold voltage	V _{GS(th)}	1.0	1.5	2.0	V	$I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}$
Drain-source on-state resistance	r _{DS(ON)}	—	120	160	mΩ	$I_D = 5 \text{ A}, V_{GS} = 10 \text{ V}$
Drain-source on-state resistance	r _{DS(ON)}	—	125	165	mΩ	$I_D = 5 \text{ A}, V_{GS} = 4 \text{ V}$
Drain-source on-state voltage	V _{DS(ON)}	—	0.60	0.80	V	$I_D = 5 \text{ A}, V_{GS} = 10 \text{ V}$
Forward transfer admittance	y _{fs}	—	18	_	S	$I_D = 5 \text{ A}, V_{DS} = 10 \text{ V}$
Input capacitance	Ciss	—	1800	_	pF	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V},$
Output capacitance	Coss	—	180	_	pF	f = 1MHz
Reverse transfer capacitance	Crss	_	85	—	pF	
Turn-on delay time	t _{d(on)}	_	17	—	ns	$V_{DD} = 80 V, I_D = 5 A,$
Rise time	tr	_	23	—	ns	V _{GS} = 10 V,
Turn-off delay time	t _{d(off)}	_	150	—	ns	$R_{GEN} = R_{GS} = 50 \ \Omega$
Fall time	t _f	—	75	—	ns	
Source-drain voltage	V _{SD}	—	1.0	1.5	V	$I_{S} = 5 \text{ A}, V_{GS} = 0 \text{ V}$
Thermal resistance	R _{th(ch-c)}	_	_	3.57	°C/W	Channel to case

90

V4

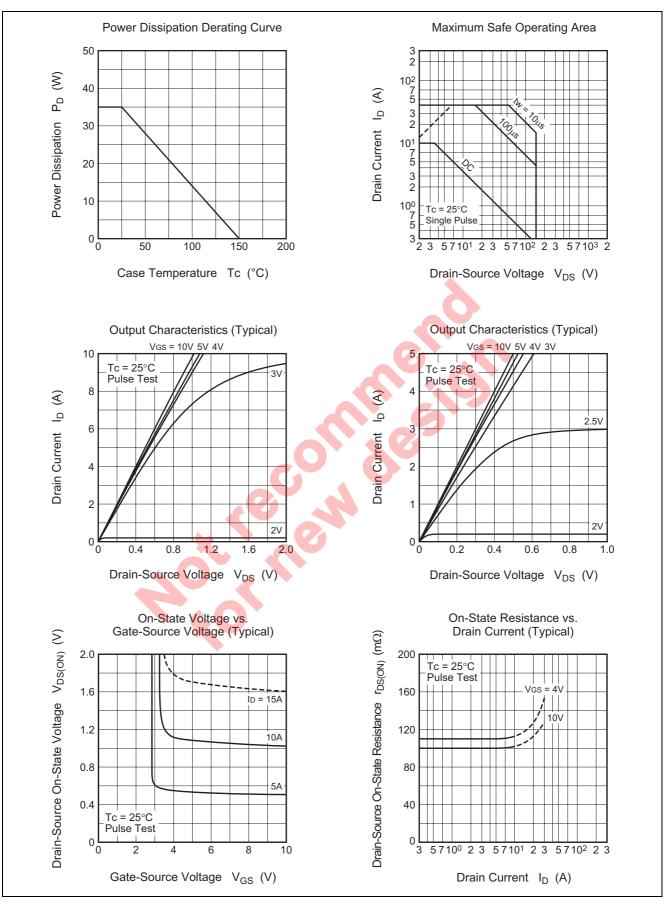
ns

 $I_{s} = 10 \text{ A}, d_{is}/d_{t} = -100 \text{ A}/\mu s$

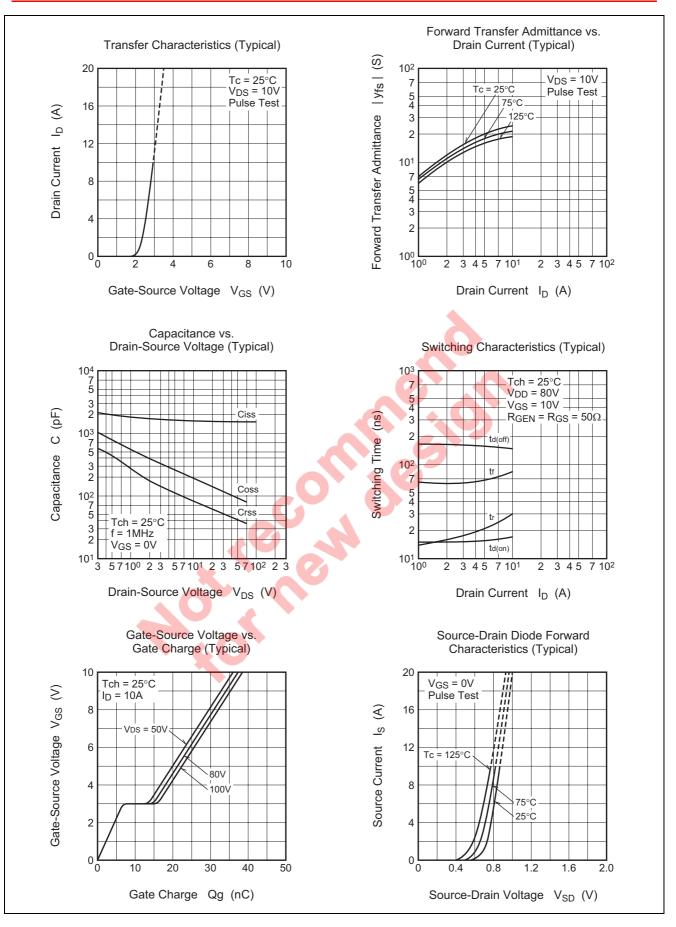
_

t_{rr}

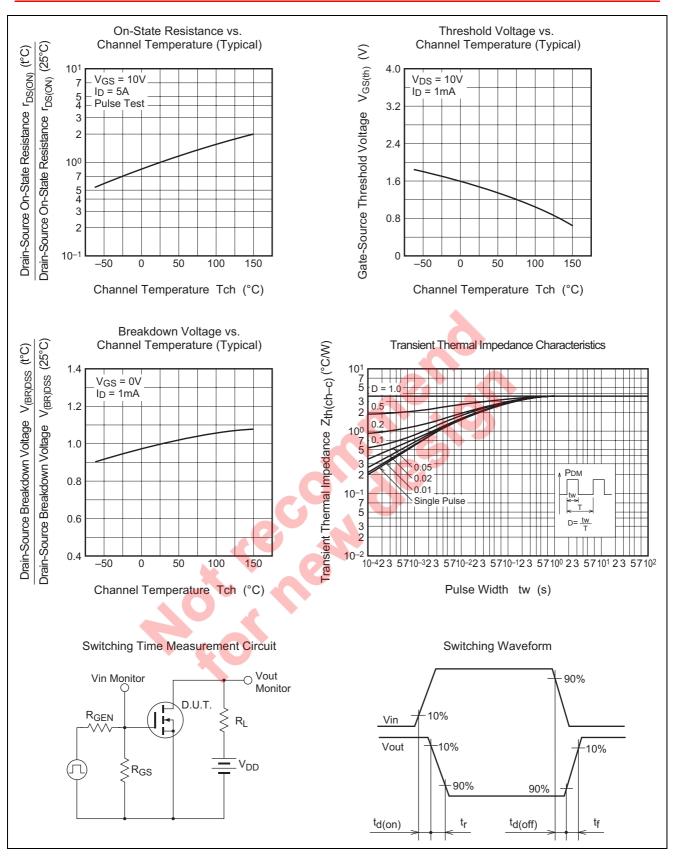
Performance Curves



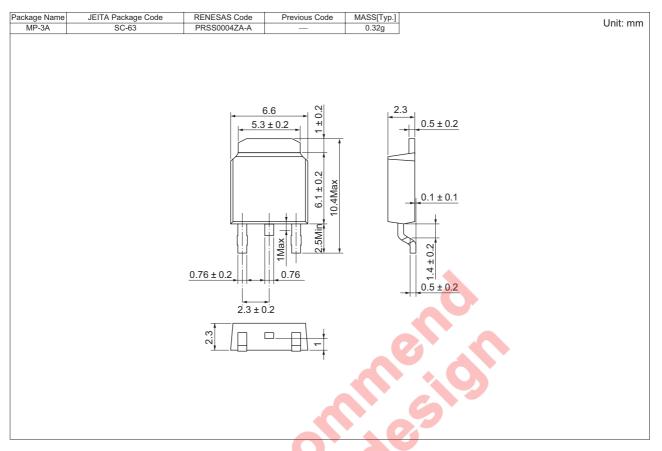








Package Dimensions



Order Code

Lead form	Standard packing	Quantity	Standard order code	Standard order code example
Surface-mounted type	Taping	3000	Type name – T +Direction (1 or 2) +3	FS10ASJ-3-T13
Surface-mounted type	Plastic Magazine	75	Type name	FS10ASJ-3
	(Tube)	•		

Note : Please confirm the specification about the shipping in detail.

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